



GP1M016A025HG Information



For Reference Only

Part Number GP1M016A025HG

ManufacturerGlobal Power Technologies GroupCategoryDiscrete Semiconductor Products
Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 250V 16A TO220

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









GP1M016A025HG Specifications

Manufacturer Part Number	GP1M016A025HG
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	250V
Current - Continuous Drain (Id) @ 25°C	16A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	944pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	93.9W (Tc)
Rds On (Max) @ Id, Vgs	240 mOhm @ 8A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220
Package / Case	TO-220-3
	Report errors?

GP1M016A025HG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

GP1M016A025HG Payment Methods



















GP1M016A025HG Shipping Methods













If you have any question about GP1M016A025HG, please do not hesitate to contact us!

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